

C₆₀ fulleren molekulasi rekonstruksiya qilinmagan kremniy Si(111) sirtida adsorbsiya jarayonlarini kompyuterda modellashtirish va tahlili.**Annotatsiya**

Mazkur tadqiqot ishida C₆₀ fulleren molekulasi rekonstruksiya qilinmagan kremniy Si(111) sirti bilan o'zaro ta'sir jarayonlari molekulyar dinamika usuliga asoslangan ochiq paket LAMMPS dasturi yordamida simuliyatsiya qilindi. Fulleren molekulasi berilgan taglik sirtida adsorbsiya energiyasi energiyani minimal qilish orqali aniqlangan bo'lib, taglik va fulleren molekulasi tashkil etuvchi atomlar orasidagi o'zaro ta'sirlar Tersoff atomlararo potentsiali yordamida ifodalangan. Shuningdek, o'zaro ta'sir vaqtida yuzaga keluvchi Si-C bog'lar uzunligi va ushbu bog'larning tabiati aniqlanib, erishilgan har bir konfiguratsiya uchun adsorbsiyaning kimyoviy yoki fizik xarakterda ekanligidan ularning barqarorligi haqida xulosalar qilingan.

Kalit so'zlar: fulleren, kremniy, adsorbsiya, konfiguratsiya, geksagon, pentagon, sirt, adsorbsiya energiyasi, bog', bog' uzunligi, potentsial, kovalent bog'lar, atom.

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Ташкент, ул. Университетская, 4.e-mail: fizik25@mail.ru**Компьютерное моделирование и анализ процессов адсорбции молекулы фуллерена C₆₀ на нереконструированной поверхности кремния Si(111).****Аннотация**

В данной исследовательской работе процессы взаимодействия молекулы фуллерена C₆₀ с нереконструированной поверхностью кремния Si(111) моделировались с использованием пакета с открытым исходным кодом LAMMPS на основе метода молекулярной динамики. Энергия адсорбции молекулы фуллерена на заданной поверхности подложки определялась методом минимизации энергии, а взаимодействия между атомами, составляющими подложку, и молекулой фуллерена выражались с использованием межатомного потенциала Терсоффа. Также были определены длина связей Si-C, образующихся в ходе взаимодействия, и природа этих связей, а также сделаны выводы о стабильности адсорбции, будь то химическая или физическая природа, для каждой достигнутой конфигурации.

Ключевые слова: фуллерен, кремний, адсорбция, конфигурация, шестиугольник, пятиугольник, поверхность, энергия адсорбции, связь, длина связи, потенциал, ковалентные связи, атом.

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Computer modeling and analysis of adsorption processes of C₆₀ fullerene molecule on unreconstructed silicon Si(111) surface.

Abstract

In this study, the interaction processes of the C₆₀ fullerene molecule with the unreconstructed silicon Si(111) surface were simulated using the open package LAMMPS program based on the molecular dynamics method. The adsorption energy of the fullerene molecule on a given substrate surface was determined by energy minimization, and the interactions between the atoms constituting the substrate and the fullerene molecule were expressed using the Tersoff interatomic potential. Also, the length of the Si-C bonds formed during the interaction and the nature of these bonds were determined, and conclusions were made about the stability of the adsorption for each configuration achieved, whether it was of a chemical or physical nature.

Key words: fullerene, silicon, adsorption, configuration, hexagon, pentagon, surface, adsorption energy, bond, bond length, potential, covalent bonds, atom.

Kirish

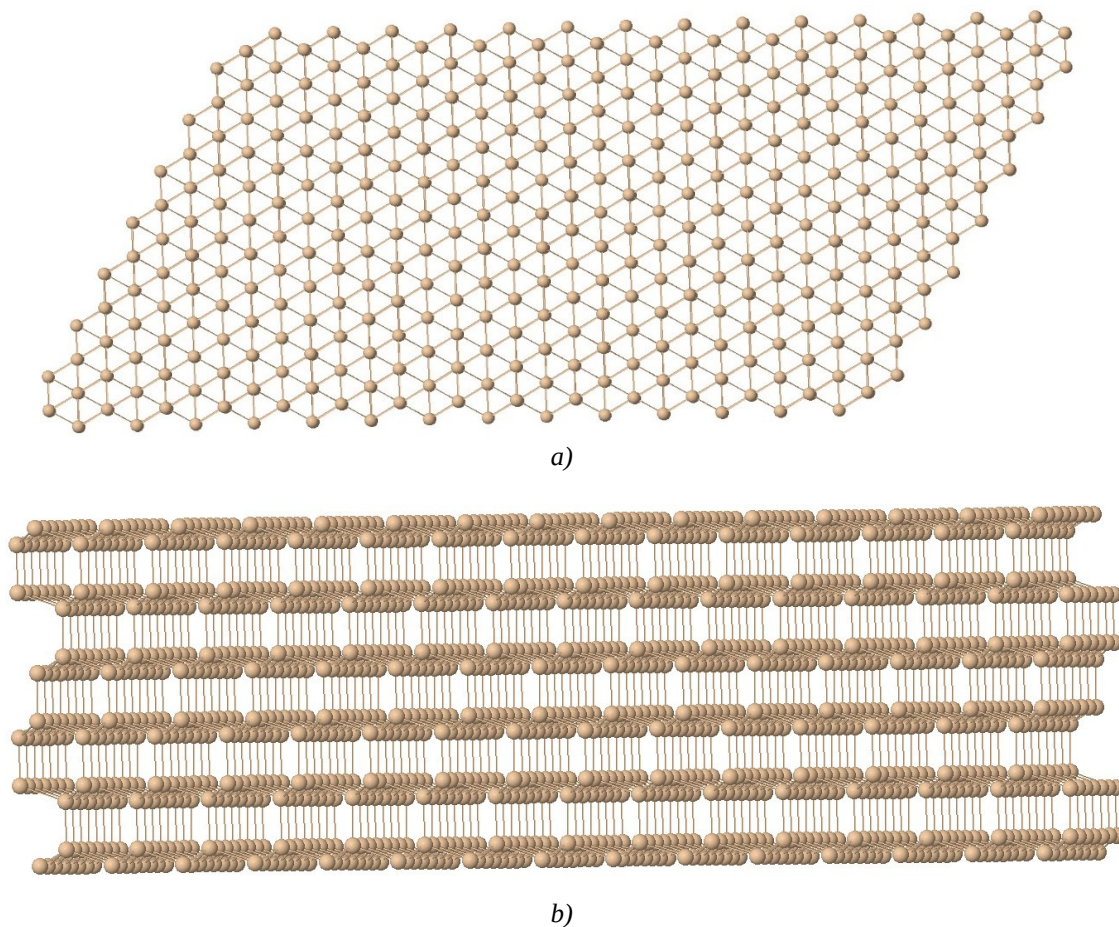
Uch o'lchamli yirik organik molekulalarning turli yarimo'tkazgich qattiq sirtlarda adsorbsiyasi istiqbolli texnologik yechimlarni taklif etayotganligi sababidan intensiv o'sib borayotgan yo'nalishlardan biri hisoblanadi. Shu singari potensial istiqbolga ega tadbirlardan biri kremniy taglik sirtida adsorbsiyalangan fulleren molekulalarining kelajak hisoblash mashinalari bo'lmish kvant kompyuterlarida qattiq-holat kubitlarida foydalanish mumkin ekanligidir [1-4]. Fulleren molekulalarining o'ziga xos xilma-xil o'lcham va shakllarga ega ekanligidan, ulardan yoqilg'i sanoati [5-7], kompozit materiallar [8-10] va quyosh batareyalari, biotibbiyot [11-14] bilan bog'liq sohalarda qo'llanilishi faqatgina fullerenlargagina xos xususiyatlari bilan amaliy ahamiyatga ega hisoblanadi. C₆₀ fulleren molekulasi metall va yarimo'tkazgich materiallar sirti bilan ta'sirlashuv jarayoni STM, XPS va boshqa bir qator qurilmalar yordamida eksperimental tarzda o'rganilgan [15,16]. Rekonstruksiya qilingan kremniy Si(001) 2×1 va Si(111) 7×7 sirtida C₆₀ fulleren molekulasi adsorbsiyasi zichlik funksional nazariyasi (DFT) va molekulyar dinamika (MD) usulida tadqiq qilingan [17-20]. Shunga qaramasdan, C₆₀ fulleren molekulasi rekonstruksiya qilinmagan kremniy Si(111) sirtida adsorbsiya jarayonini nazariy jihatdan kam tadqiq qilingan. rekonstruksiya qilinmagan kremniy Si(111) sirti birinchi va ikkinchi qatlamdagi atomlar joylashuvi, ularning to'yinish darajasining boshqa kesimlardan farq qilishi fulleren C₆₀ molekulasi ushbu sirtida adsorbsiyasi (100) va (110) sirtlarida kuzatilgan adsorbsiyalardan keskin farq qiladi. Ushbu keskinlikni natijalar tahlilida bayon qilinadi. Shuningdek, kremniy Si(111) sirtidagi atomlar joylashuv strukturalari fulleren molekulasi

Mazkur tadqiqot ishining maqsadi – rekonstruksiya qilinmagan kremniy Si(111) sirtida C₆₀ fulleren molekulalarining adsorbsiya jarayonlarini o'rganish bilan birgalikda, adsorbsiyalanish konfiguratsiyalari va ular orasidan barqaror adsorbsiya holatlarini aniqlash, shuningdek ushbu jarayonda yuzaga keluvchi Si-C bog'lanishlarning uzunligi va ularning tabiatini tadqiq qilishdan, shuningdek, chiqarilgan xulosalar asosida ba'zi tadqiqot yoki tadqiqot natijalari tadbiriq etiladigan amaliy ishlarga tavsiyalar berishdan iborat.

Metodologiya

Ushbu ishda ko'rib chiqilgan barcha o'zaro ta'sir jarayonlari MD usuliga asoslangan ochiq manba LAMMPS [21] paket dasturidan foydalanilgan holda modelashtirilgan bo'lib, C₂₀ fulleren molekulalarining koordinatalari Nanotube Modeller [22] dasturi yordamida olingan. O'zaro ta'sir jarayonlari, ya'ni kuzatilgan adsorbsiya jarayonlari JMOL [23] vizualizatsiya dasturi yordamida namoyish qilingan. Taglik sifatida olingan kremniy monokristali o'lchamlari 54×27×16 Å bo'lgan rombik parallelepipeddan bo'lib, u 1432 ta kremniy atomidan iborat. Kremniy taglik va C₆₀ fulleren molekulasini atomlari orasidagi o'zaro ta'sir ikkinchi tartibli Tersoff [24] atomlararo potentsiali yordamida ifoda qilingan. JMOL dasturi yordamida oldindan C₆₀ molekulasi adsorbsiyasi kuzatilgan konfiguratsiyalari vizualizatsiya qilindi va shu bilan birgalikda, kremniy monokristalining rekonstruksiya qilinmagan (111) kesimli sirti ham ushbu dastur yordamida hosil qilindi. Olingan natijalarga o'lcham effektining ta'sir mavjud emasligi, boshqa o'lchamli tagliklar yordamida tekshirib ko'rib, mazkur effektning ushbu jarayonda hech qanday ahamiyatga ega emasligi aniqlandi. Tanlangan haroratni o'zgarish saqlab turish uchun Noze-Guvern termostati [25] dan foydalanildi. Verle tezlik-vaqt sxemasi 1.0 fs vaqt qadami bilan integratsiyalandi. Simulyatsiya vaqtida sodir bo'lishi mumkin

bo'lgan ilgari tanilgan harakatlarni hisobga olmaslik maqsadida sistema massa markazi qo'zg'almas qilib tanlandi. Barcha simuliyatsiyalar muvozanatli holatni egallaganlaricha 100 ns dan 200 ns gacha vaqt oralig'ida amalga oshirildi. Bundan tashqari, har bir konfiguratsiyaga mos adsorbsiya jarayoniga tegishli kattaliklar molekulaning taglikka nisbatan turli balandlik holatlarida tekshirilib, ularning eng minimal qiymatlari natija sifatida olindi.



1-rasm. kremniy taglikning yuqoridan va yondan ko'rinishi.

1-rasmda C_{60} fulleren molekulasining adsorbsiyasi kuzatilgan rekonstruksiyan-magan kremniy Si(111) kesimi (a) va ushbu monokristallning yondan ko'rinishi (b) tasvirlangan.

Adsorbsiya energiyasini hisoblash

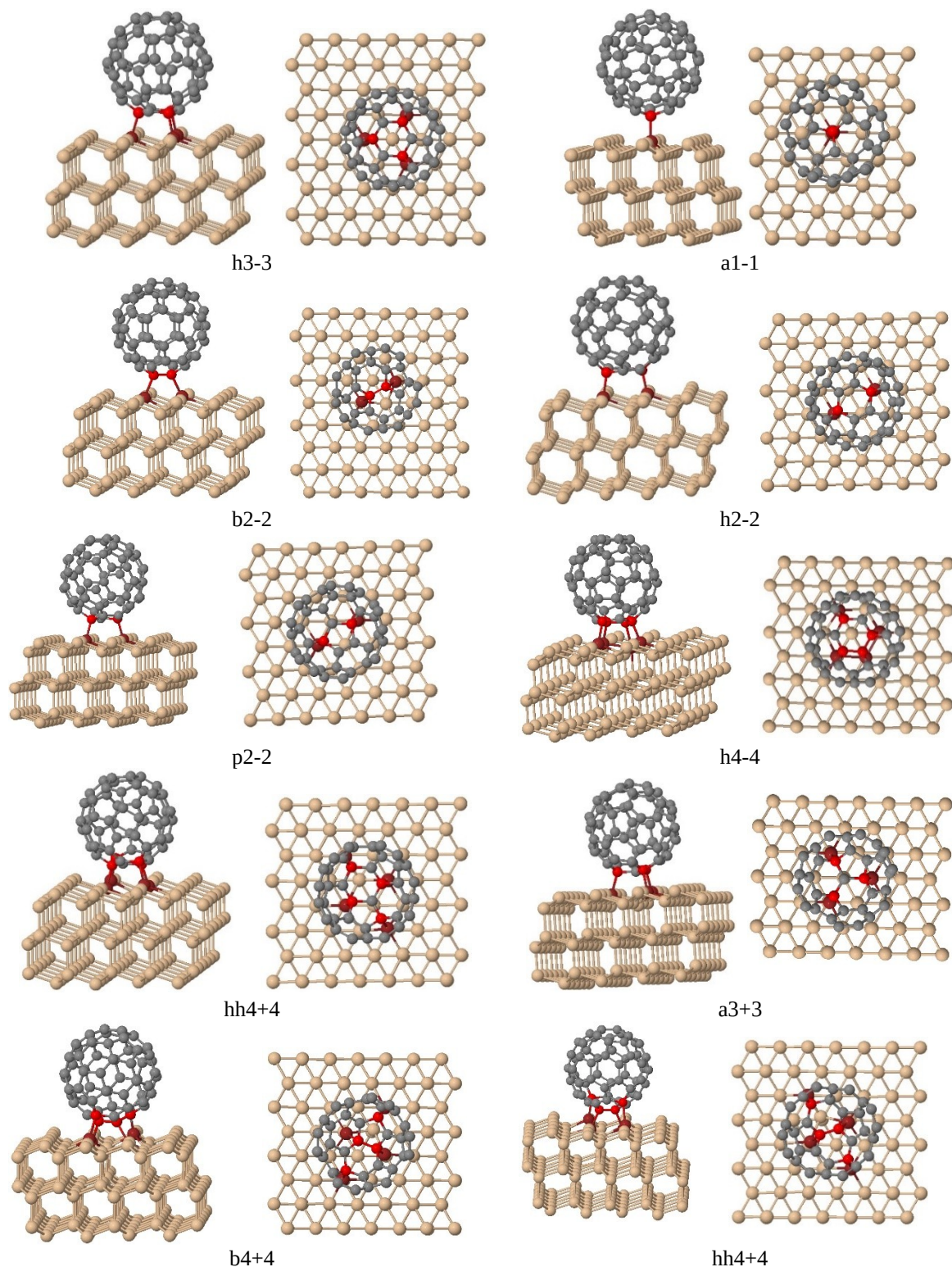
Metall yoki yarimo'tkazgichli tagliklar sirtida adsorbsiyalangan klaster, molekula yoki atomlarning sirt bilan bog'lanish energiyalari ko'pgina MD yoki DFT usuliga asoslangan nazariy ishlarda [26-29] molekula taglikka adsorbsiyalangan holatdagi butun sistema potentsial energiyasidan taglik va molekula o'zaro ta'sir holatida bo'lmagandagi yig'indi potentsial energiyalarining ayirmasiga teng bo'ladi, ya'ni

$$E_{ads} = E_{tag/mol} - (E_{tag} + E_{mol}).$$

Bunda E_{ads} – C_{60} fulleren molekulasining kremniy taglik sirtida adsorbsiyalanish energiyasi, $E_{tag/mol}$ – kremniy taglik va fulleren molekulasining o'zaro ta'sirlashuv vaqtidagi to'liq potentsial energiyasi, E_{tag} va E_{mol} mos ravishda taglik va fulleren molekulasining o'zaro ta'sirlashmagan vaqtidagi, ya'ni yakka holatdagi potentsial energiyalari hisoblanadi. Ushbu energiya qiymatlari 0 K haroratda taglik va fulleren molekularining muvozanatli holatida, energiyalarning aniqlanish shartiga mos ravishda, ular o'zaro ta'sirlashgan va yakka holatlarida LAMMPS ochiq paket dasturida energiyani minimallashtirish orqali aniqlandi.

Natijalar tavsifi va tahlili

Mazkur tadqiqot ishida C_{60} fullerene molekulasining rekonstruksiyanmagan kremniy Si(111) sirtida 10 xil konfiguratsiya bilan adsorbsiyalanishi va har bir konfiguratsiyaga mos adsorbsiya energiyalari, o'zaro ta'sir jarayonida yuzaga keluvchi har bir Si-C bog' uzunligi va ushbu bog'larning kovalent yoki nokoalent bog'lanish tabiatiga ega ekanligiga ko'ra kimyoviy yoki fizik bog'lanish xarakteriga ega ekanligi aniqlandi. Tadqiqot ishida aniqlangan miqdoriy natijalar quyidagi 1- jadvalda o'z aksini topgan.



2-rasm. C_{60} fullerene molekulasining rekonstruksiyanmagan kremniy Si(111) sirtida kuzatilgan adsorbsiyalarining yondan va yuqoridan ko'rinishi. Bunda Si-C bog'lanishlarni yuzaga keltirgan kremniy va uglerod atomlari mos ravishda jigarrang va qizil ranglarda ifodalangan.

1- jadvalning birinchi ustunida fullerene molekulasining adsorbsiyalanish konfiguratsiyalari berilgan bo'lib, ushbu klassifikatsiya – fullerene molekulasidagi pentagon, geksagon, bridj va tugundagi atomlarning bog'lanishda ishtirok etuvchi soni bilan belgilashga asoslangan. Masalan, C_{60} fullerene molekulasida geksagoni (hexagon) dagi 3 ta

atom kremniy taglik sirtidagi uchta kremniy atomi bilan Si-C bog'lanish hosil qilgan bo'lsa, ushbu konfiguratsiya h3-3 kabi belgilandi.

1- jadval. C₆₀ fulleren molekulasiining taglik sirtida adsorbsiyalanish konfiguratsiyalari va ularga mos adsorbsiya energiyalari va bog' uzunliklari.

№	Konfiguratsiya	E _{ads} (eV)	λ (Å)
1	h3-3	4.22	1.95-1.96
2	a1-1	1.63	1.94
3	b2-2	1.75	2.02
4	h2-2	2.80	1.94-1.95
5	p2-2	2.87	1.95
6	h4-4	1.92	2.09-2.12
7	hh4+4	2.59	1.92-2.23
8	a3+3	4.71	1.9-2.05
9	b4+4	2.78	1.91-2.07
10	hh4+4	2.13	1.97-2.11

1- jadvaldagi natijalarga e'tibor berilsa, h3-3 va a3-3 konfiguratsiyali adsorbsiyalarda bog'lanish energiyalari tadqiqot ishida kuzatilgan eng kichik adsorbsiya energiyasidan deyarli uch marta katta qiymatga ega ekanligini ko'rish mumkin. Bunday keskinlikni ushbu holatlarning har birida kuzatilgan ikkita kovalent bog'lar sababli deyish mumkin, shuningdek ushbu holatlarda C₆₀ fulleren molekulasiining pentagonal konturidagi C-C juft bog'lar uzulib, kremniy atomi bilan Si-C kovalent bog'lar hosil qiladi. Buni adsorbsiyadan oldin 1.48 Å uzunlikdagi C-C juft bog'larning adsorbsiyadan keyin 1.54 Å uzunlikdagi C-C yakka bog'ga aylanishida ko'rishimiz mumkin. Kuzatilgan b2-2 konfiguratsiyali adsorbsiyada bog'lanish energiyasi 1.75 eV ni tashkil qilib, bu holatda ikkita 2.02 Å uzunlikdagi fizik bog' (Van der Waals bog'lari) hosil bo'lgan bo'lib, bunday deyishimizga sabab, har bir bog'ga to'g'ri keluvchi o'rtacha bog'lanish energiyasi 1 eV dan kichik va shuningdek, adabiyotlarda keltirilgan uzunligi 1.93 – 1.94 Å atrofida [30] bo'ladigan S-C kovalent bog' uzunligidan katta. Bu kabi tahlilga tayanadigan bo'lsak, ushbu tadqiqotda olingan quyidagi konfiguratsiyadagi adsorbsiyalarni kimyoviy adsorbsiya sifatida tasdiqlash mumkin: h3-3, a1-1, h2-2, p2-2, hh4+4, a3+3 va b4+4.

Xulosa

Olingan natijalarni o'zaro solishtirma tahlil qilish va turli kesimli kremniy tagliklar sirtida fulleren C₆₀ molekulasiining adsorbsiyasini MD usulida modellashirish orqali olingan natijalar bilan taqqoslab quyidagiga xulosalarga kelindi: fulleren C₆₀ molekulasini rekonstruksiya qilgan kremniy Si(111) taglikning faqat birinchi qatlamidagi kremniy atomlari bilan Si-C bog'lanishlarni hosil qiladi; fulleren C₆₀ molekulasiidagi C=C juft bog'lar uzulib, kremniy atomi bilan Si-C kovalent bog' hosil qiladi va ushbu bog'lar hisobiga C₆₀ molekulasiining sirtidagi adsorbsiyasi barqaror bog'lanish kasb etadi; adsorbsiya energiyasi ta'sirlashuvda yuzaga keluvchi Si-C bog'lar soniga bog'liq bo'ladi; fulleren C₆₀ molekulasini rekonstruksiya qilgan kremniy Si(111) kesimli taglikda adsorbsiyasi kimyoviy va fizik (Van der Waals) bog'lari yuzaga keladi; fulleren molekulasini ta'sirida Si-C bog'lanishda ishtirok etuvchi kremniy atomlariga ega Si-Si bog'lanishlarda kichik o'zgarishlar bo'lib, buning natijasida ushbu bog'lar uzunligi ortadi va o'zaro ta'sir potensial energiyasining absolyut qiymati kamayadi. Shuningdek, fulleren C₆₀ molekulasiining kremniy Si(100) [31] va nuqsonli Si(100) [32] sirtidagi adsorbsiyalarida kuzatilgan adsorbsiya energiyalariga nisbatan ko'rib o'tilgan kesimli sirtidagi adsorbsiya energiyalari kichikroq qiymatlarni qabul qilar ekan.

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